

Docket No.: 4425-224



PATENT

2814

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Jung-Yu HSIEH

U.S. Patent Application No. 10/002,978

Group Art Unit: 2814

Filed: December 6, 2001

Examiner: THAO X LE

For: METHOD OF FORMING AN ONO STRUCTURE IN ONE CHAMBER

Dear Sir:

Transmitted herewith is a Response in the above identified application.

- ☒ No additional fee is required.  
☐ Small entity status of this application has been established.  
☐ Also attached:

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The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	9	20	0	x \$ 18 =	\$ 0.00
Independent Claims	1	3	0	x \$ 86 =	\$ 0.00
If multiple claims newly presented, add \$290.00					
Fee for extension of time					
TOTAL FEE DUE					\$ 0.00

- ☐ A credit card authorization form in the amount of \_\_\_\_\_ is attached
- ☒ The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 07-1337, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

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BJH/jk

Appl. No. 10/002,978



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 10/002,978  
Applicant : Jung-Yu Hsieh et al  
Filed : December 6, 2001  
TC/A.U. : 2814  
Title : METHOD FOR FORMING AN ONO STRUCTURE  
IN ONE CHAMBER  
Examiner : LE, THAO X  
Docket No. : 4425-224

Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

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**RESPONSE**

Sir:

In response to the Official Action mailed on July 11, 2003, please  
reconsider the above-identified application as follows:

**Remarks/arguments** begin on page 2 of this paper.